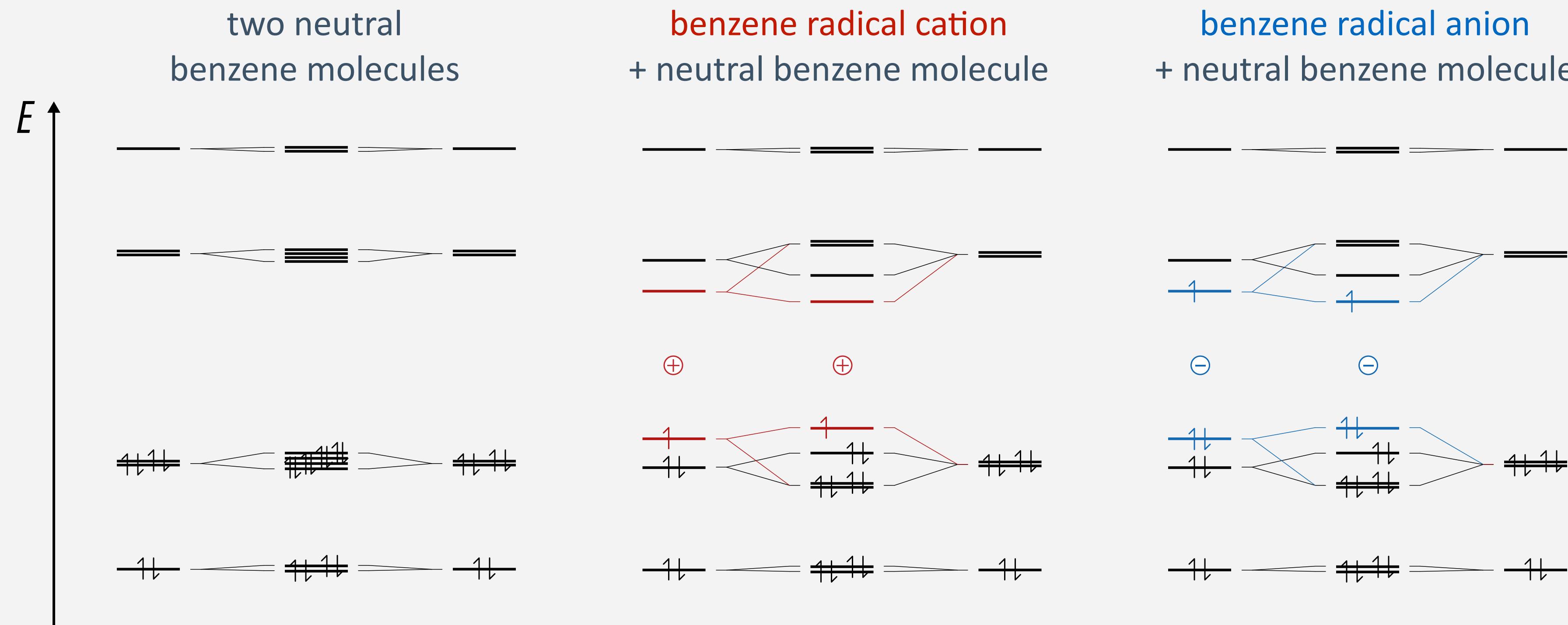

5.3 Charges in Organic Materials

Intermolecular Delocalization of a Polaron Defect

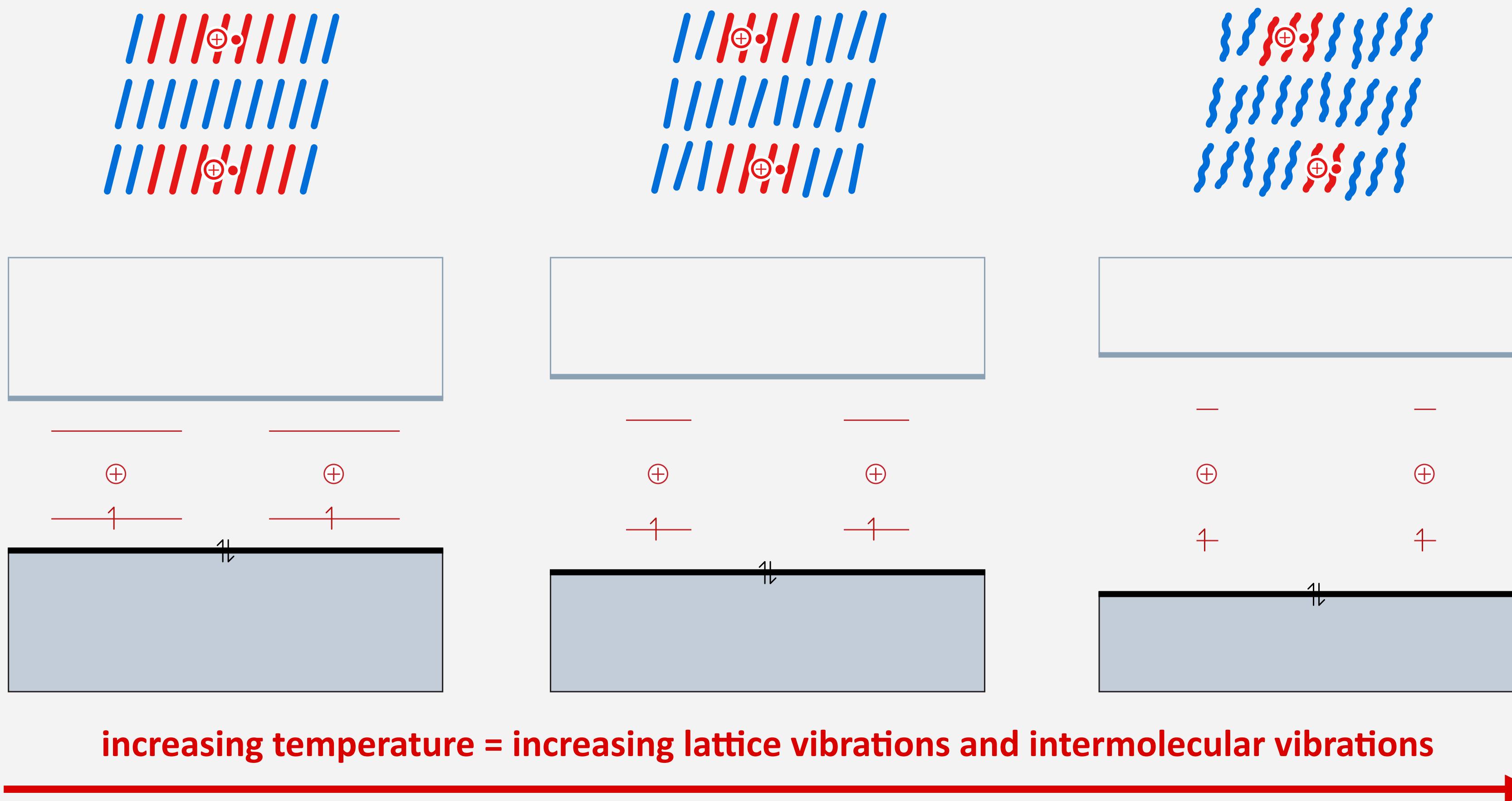
- π - π stacking between neutral molecules results in HOMO splitting and LUMO splitting
- overall electron energies increase, π - π stacking favorable due to other interactions



- π - π stacking between polarons and neutral molecules has charge-transfer character
- electronic interactions energetically more favorable and stronger, higher correlation
- π - π stacking results in intermolecular delocalization of the charge over several molecules

Delocalization and Dynamic Disorder in the Solid State

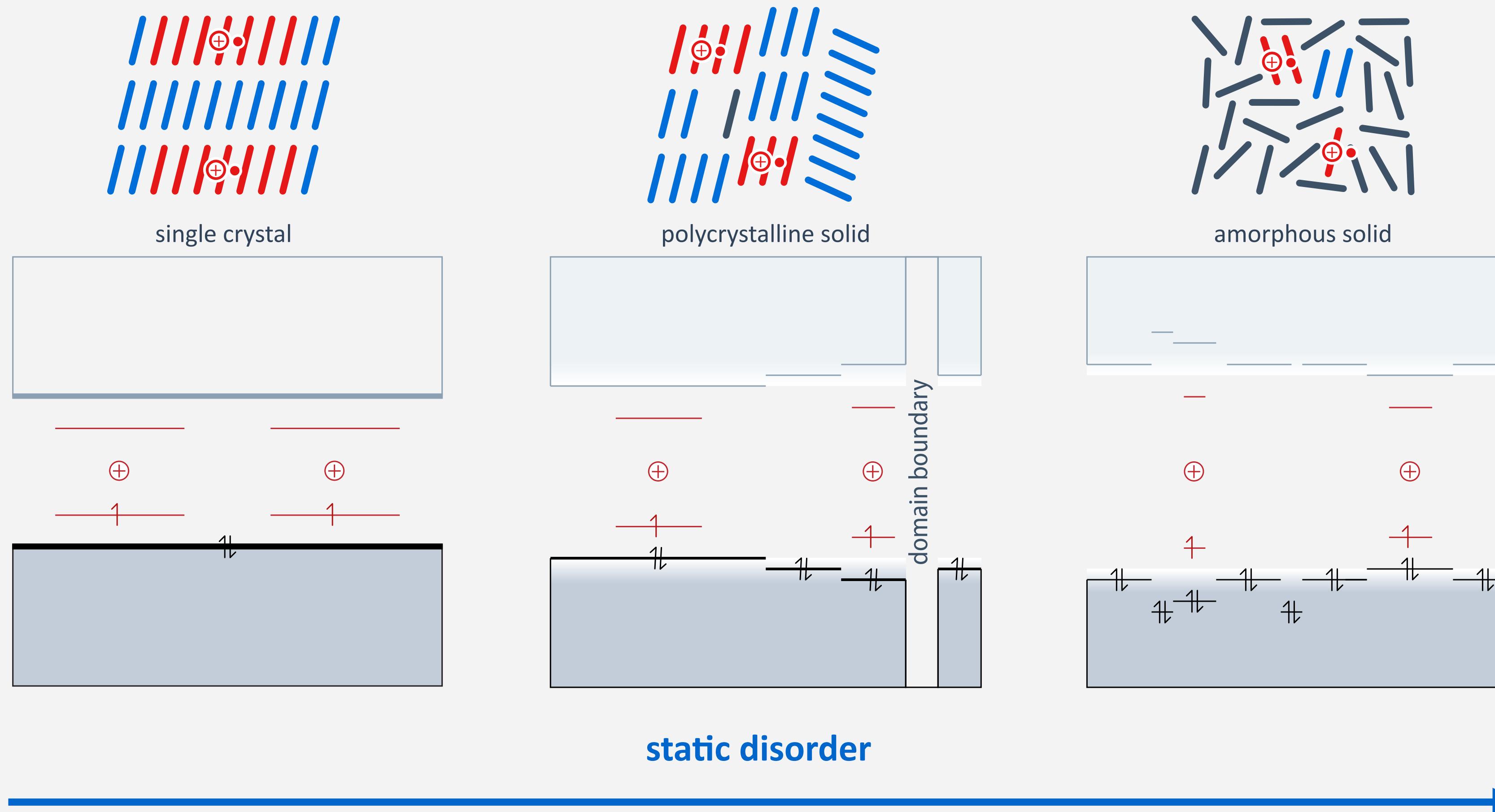
- intermolecular delocalization decreased by (supra)molecular motions in the solid state



- **dynamic disorder** increases, charge carriers more localized with increasing temperature
- band gap and also distance between valence/conduction band and polaron levels increase

Delocalization and Static Disorder in the Solid State (Crystals)

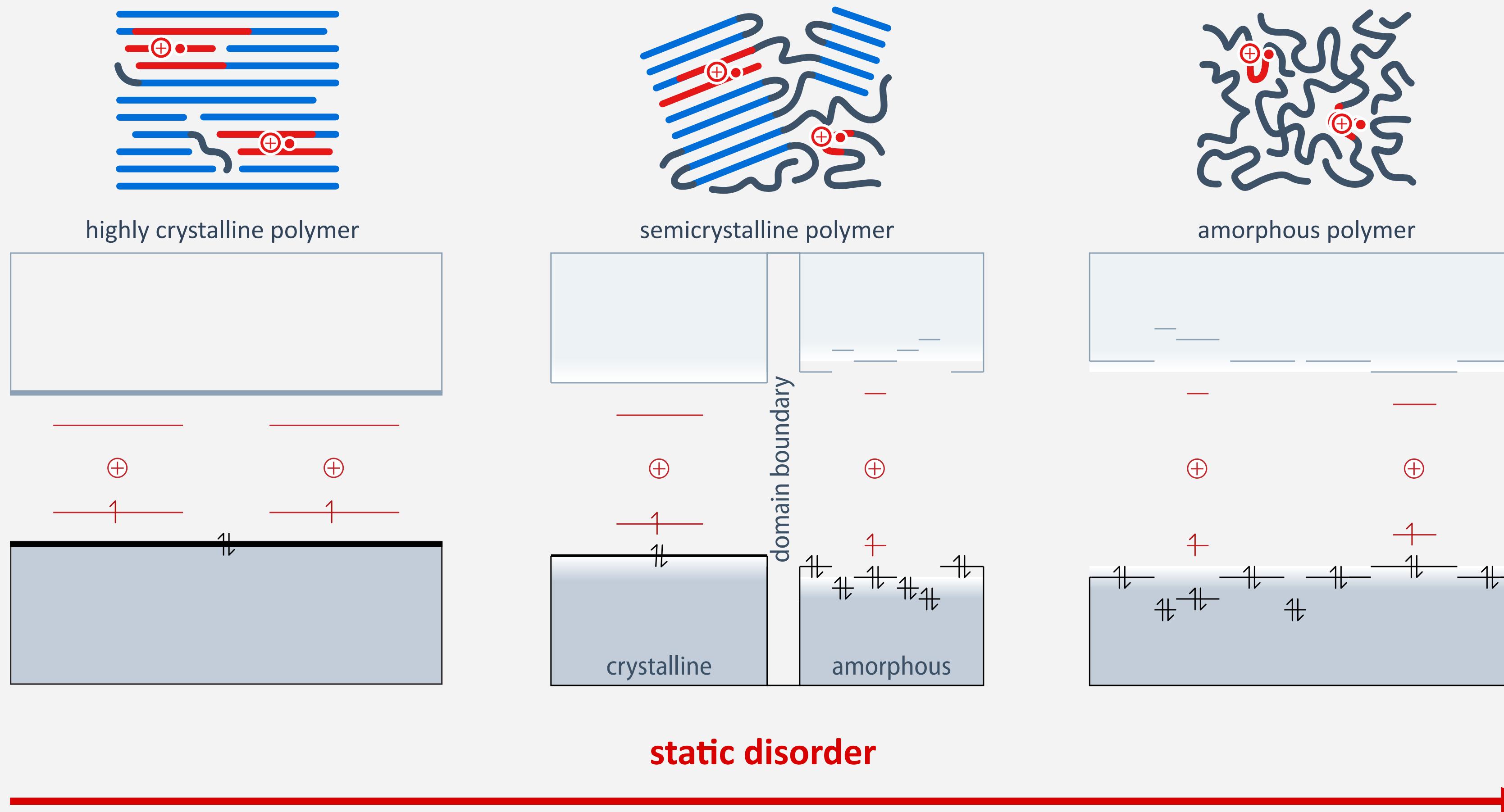
- intermolecular delocalization decreases with decreasing crystallinity and crystalline order



- charge carriers more localized with **increasing static disorder**
- **heterogeneity** includes packing defects, lattice disorder, grain & domain boundaries, impurities, ...

Delocalization and Static Disorder in the Solid State (Polymers)

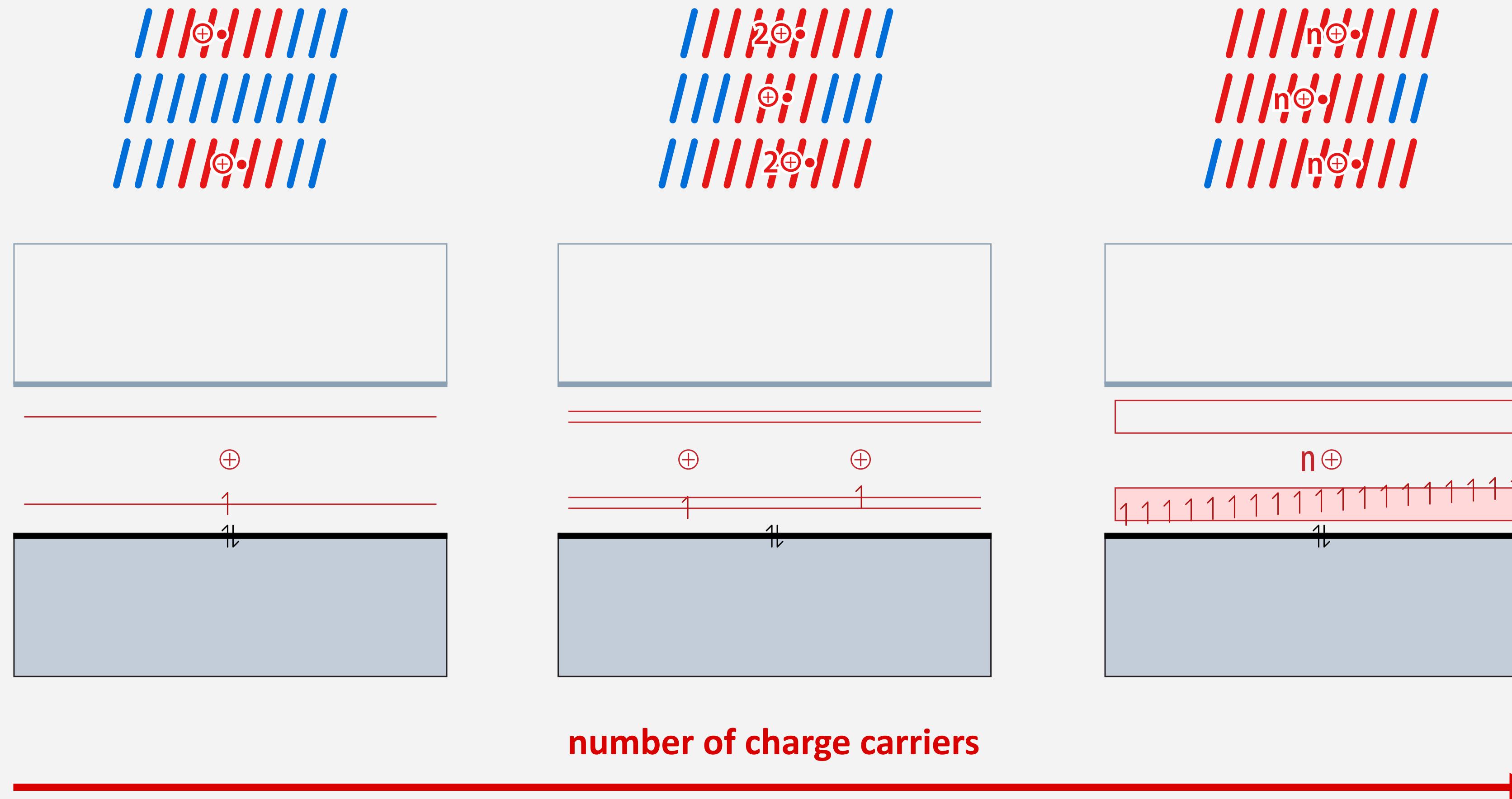
- intermolecular delocalization decreases with decreasing crystallinity and crystalline order



- charge carriers more localized with increasing static disorder
- static disorder includes decreased size of crystalline domains, defects etc. in both phases

Crystalline Organic Materials at High Charge Carrier Densities

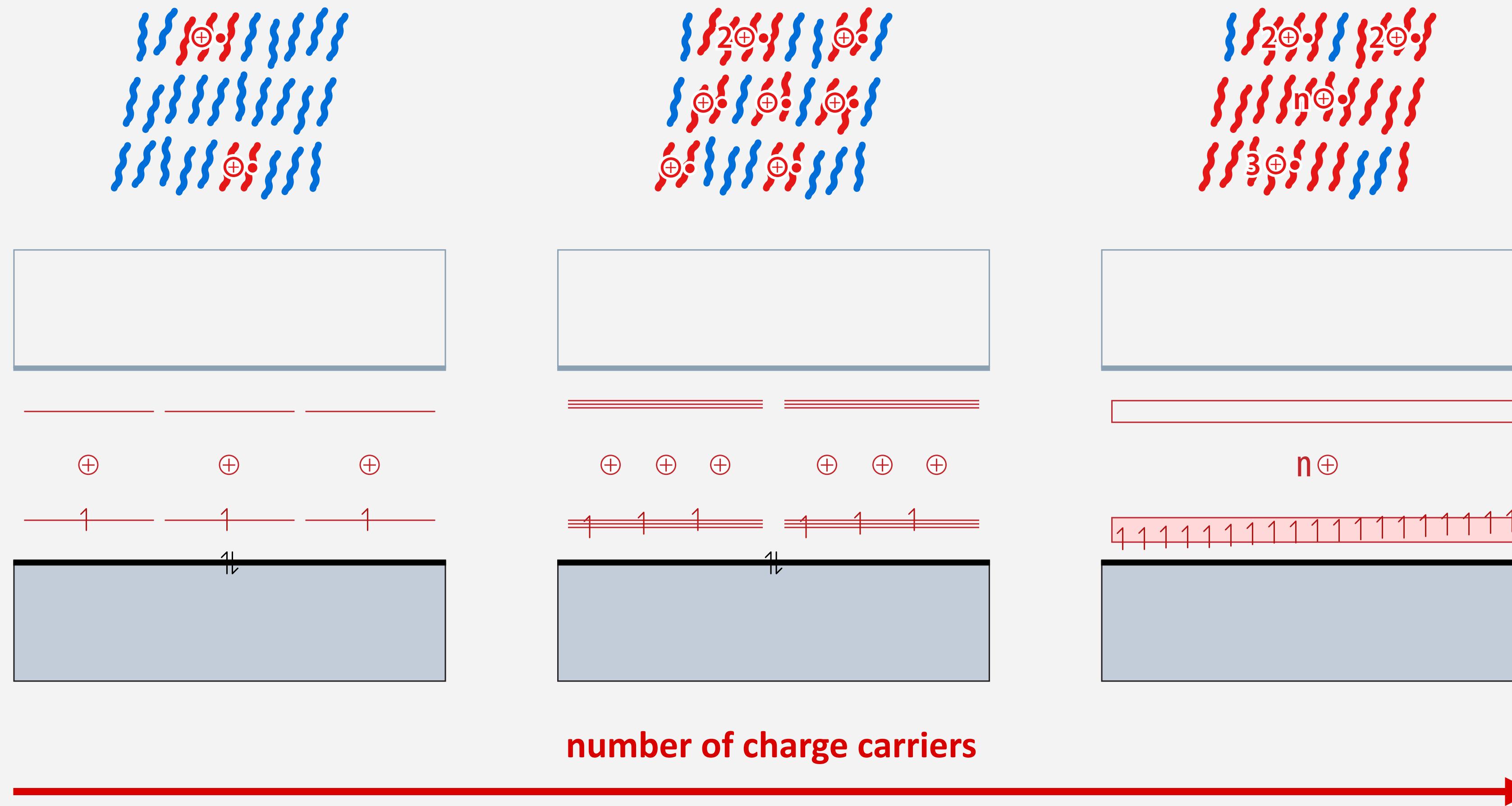
- at high doping levels, the polaron defect states start to interact with one another



- at doping of $>1/1000$ molecules, polaron every $1/10$ molecules along any lattice direction
- interaction of defect states results in MO splitting and formation of a narrow polaron band

Effect of Disorder at High Charge Carrier Densities

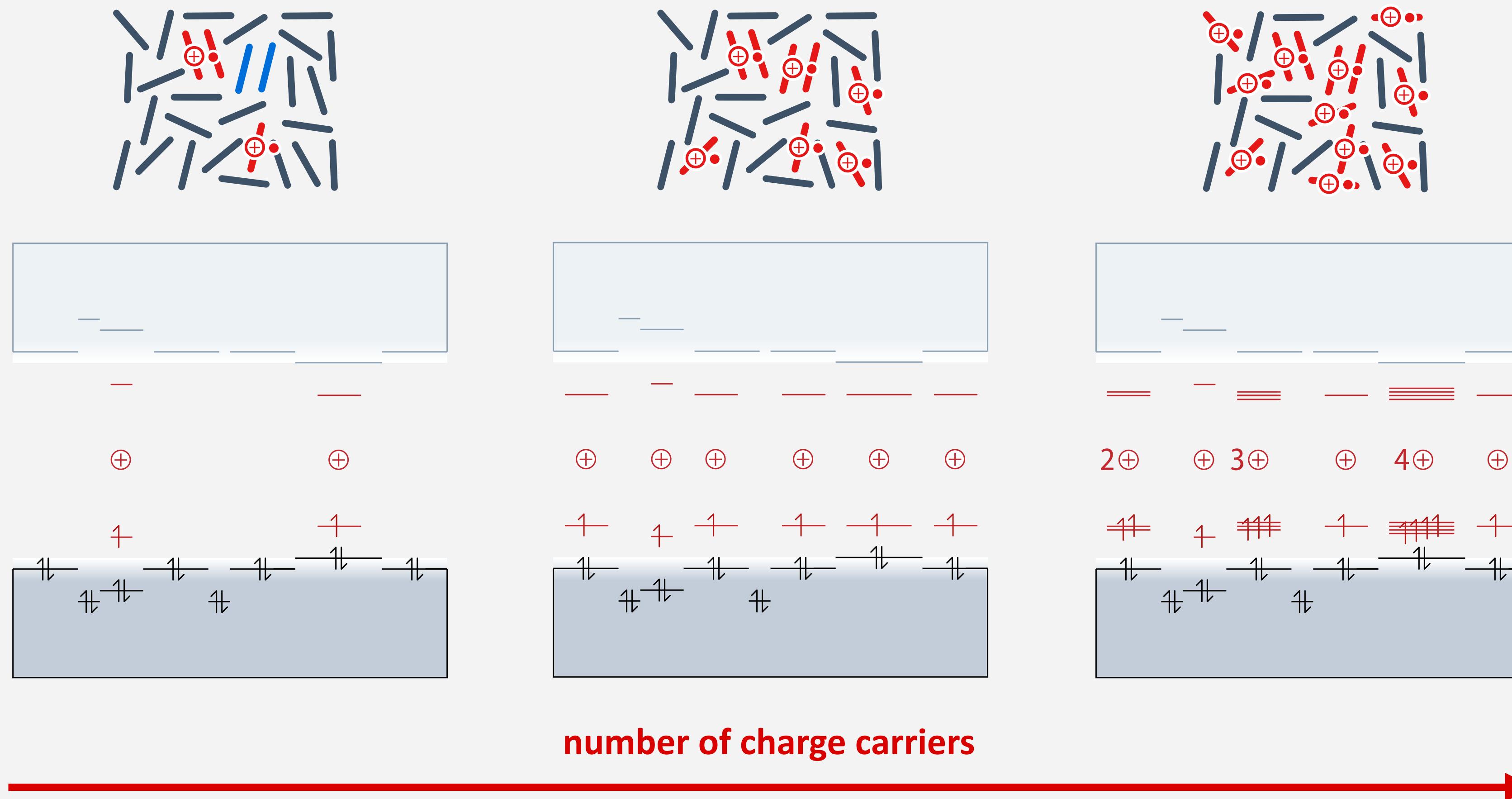
- threshold concentration increases in more disordered systems (e.g., at higher temperature)



- increase above threshold will initially locally create more extended states
- the bandwidth of the final polaron band is lower than for highly ordered systems

Highly Disordered Systems at High Charge Carrier Densities

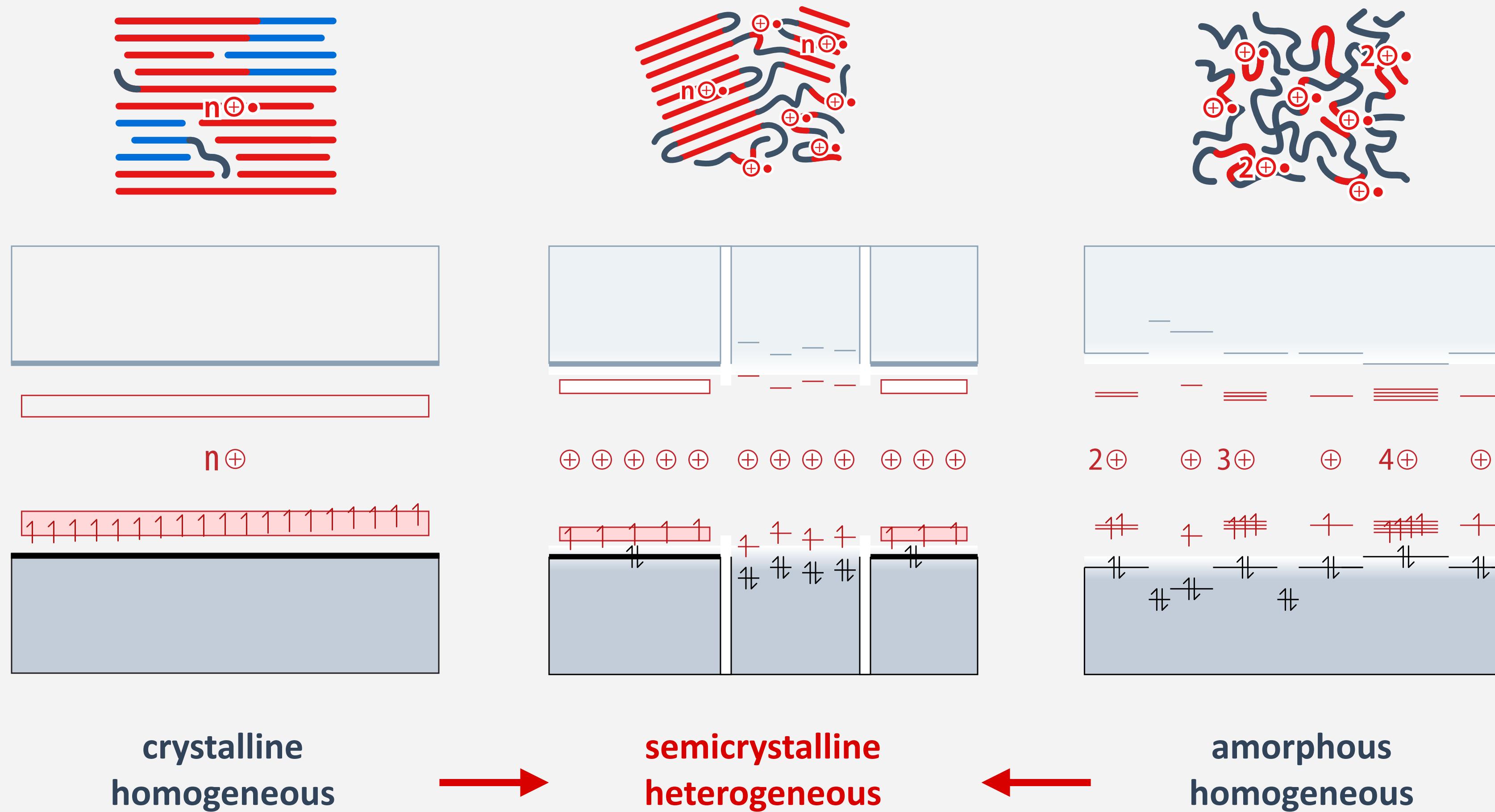
- no polaron bands even at high doping levels in highly disordered (amorphous) systems



- even in amorphous solids, polaron defects can still locally start to interact with one another
- formation of more extended polaron defect states with limited delocalization

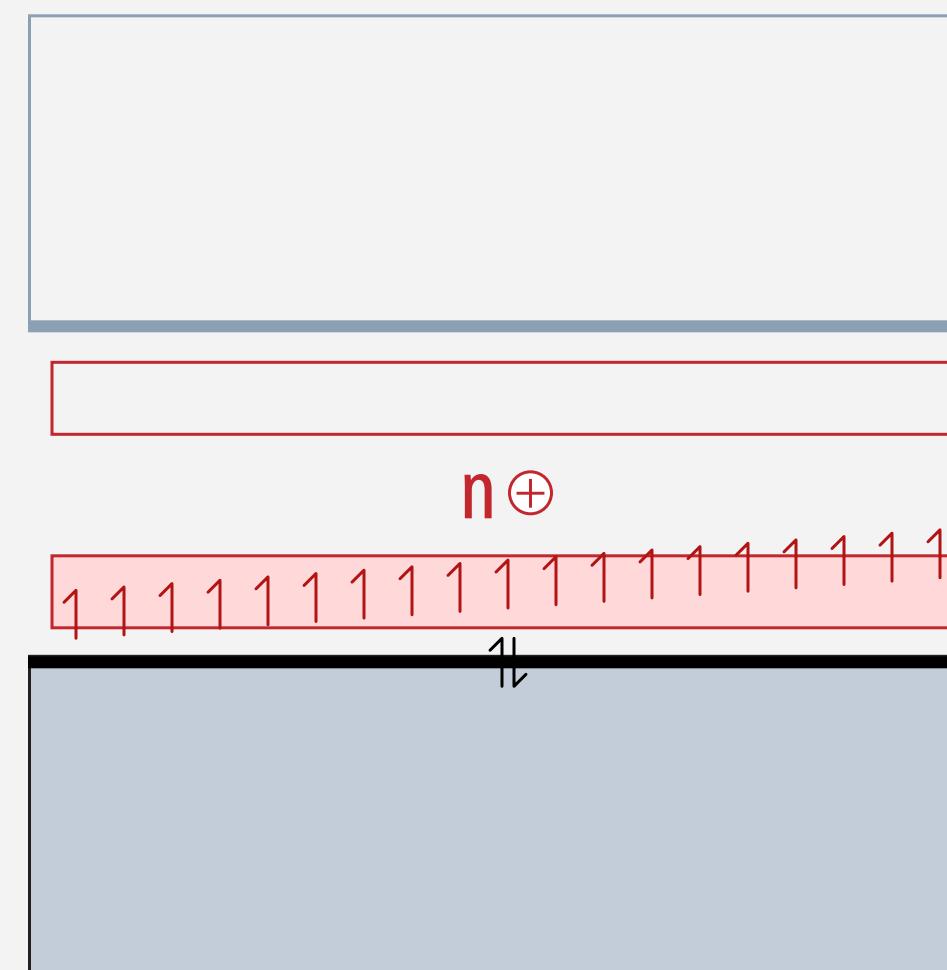
Heterogeneous Systems at High Charge Carrier Densities

- static/dynamic disorder increase from crystalline to semicrystalline to amorphous polymers



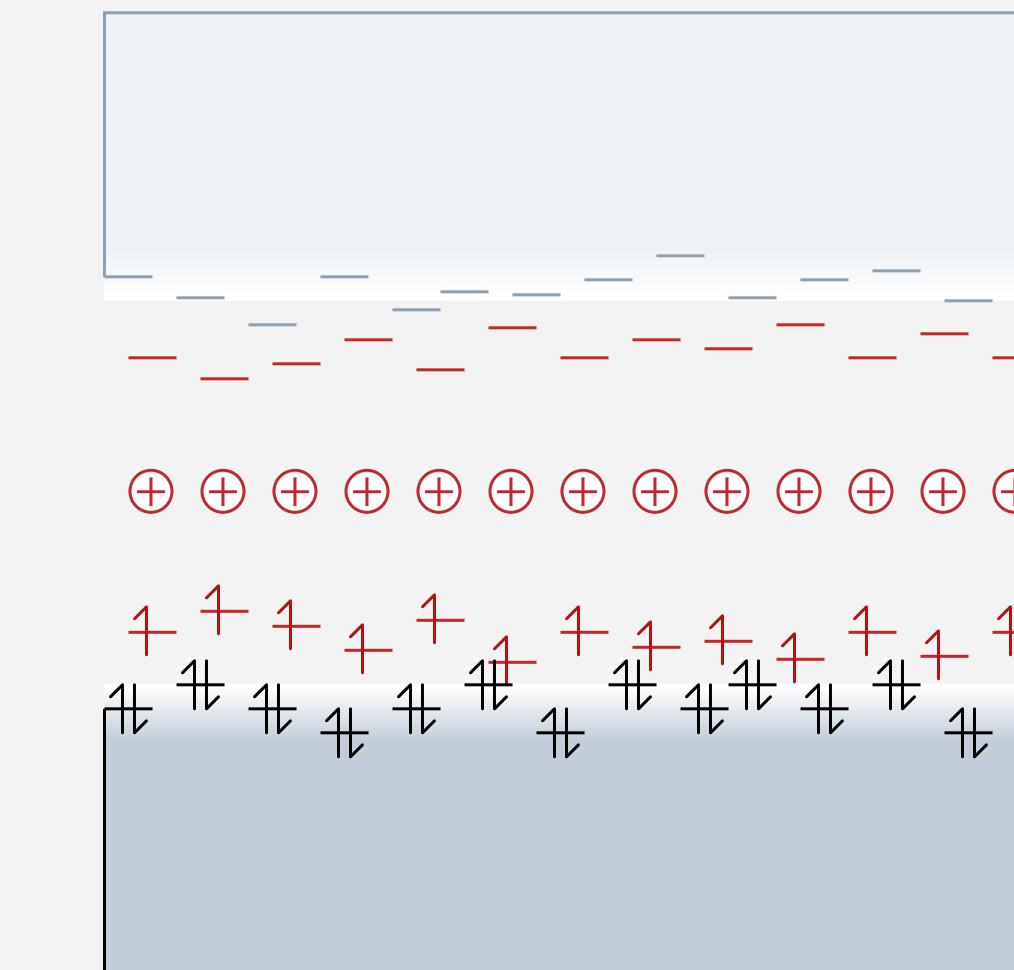
- heterogeneous correlation length and energy levels of both neutral states and polarons
- all interactions and energy levels change **abruptly** at the crystalline/amorphous interfaces

Active Regions in p-Type and n-Type Organic Semiconductors

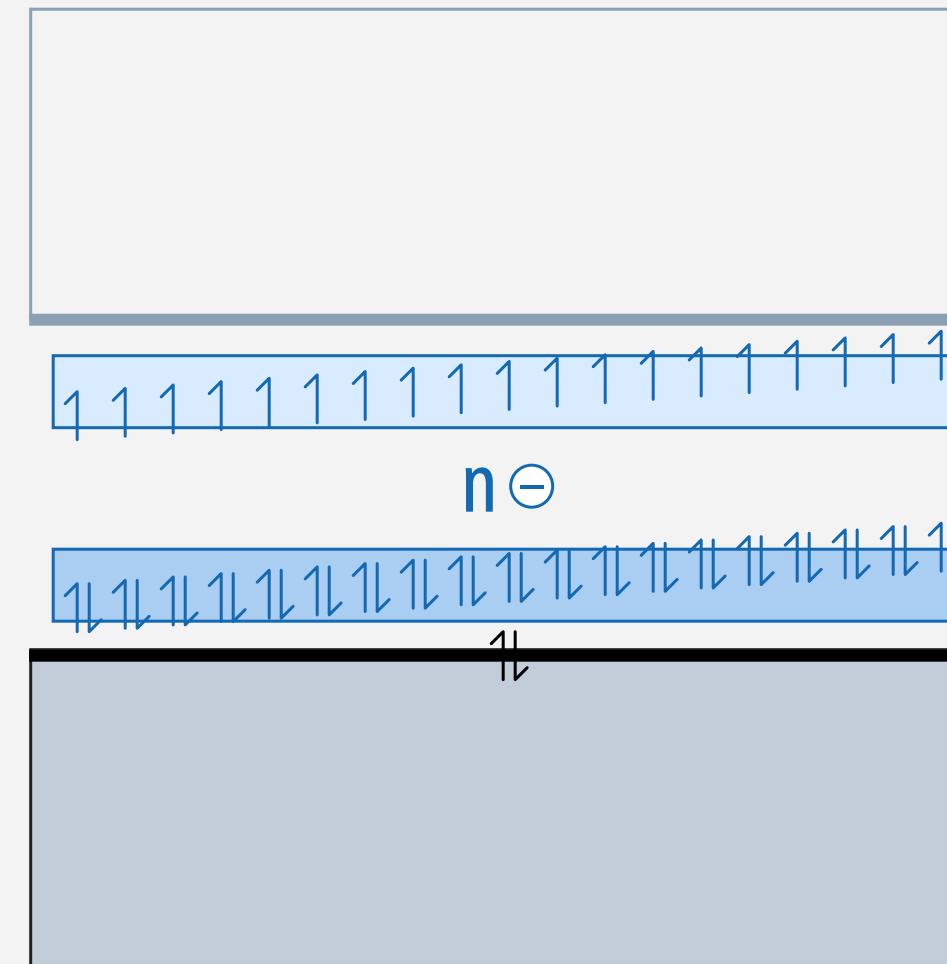


crystalline material

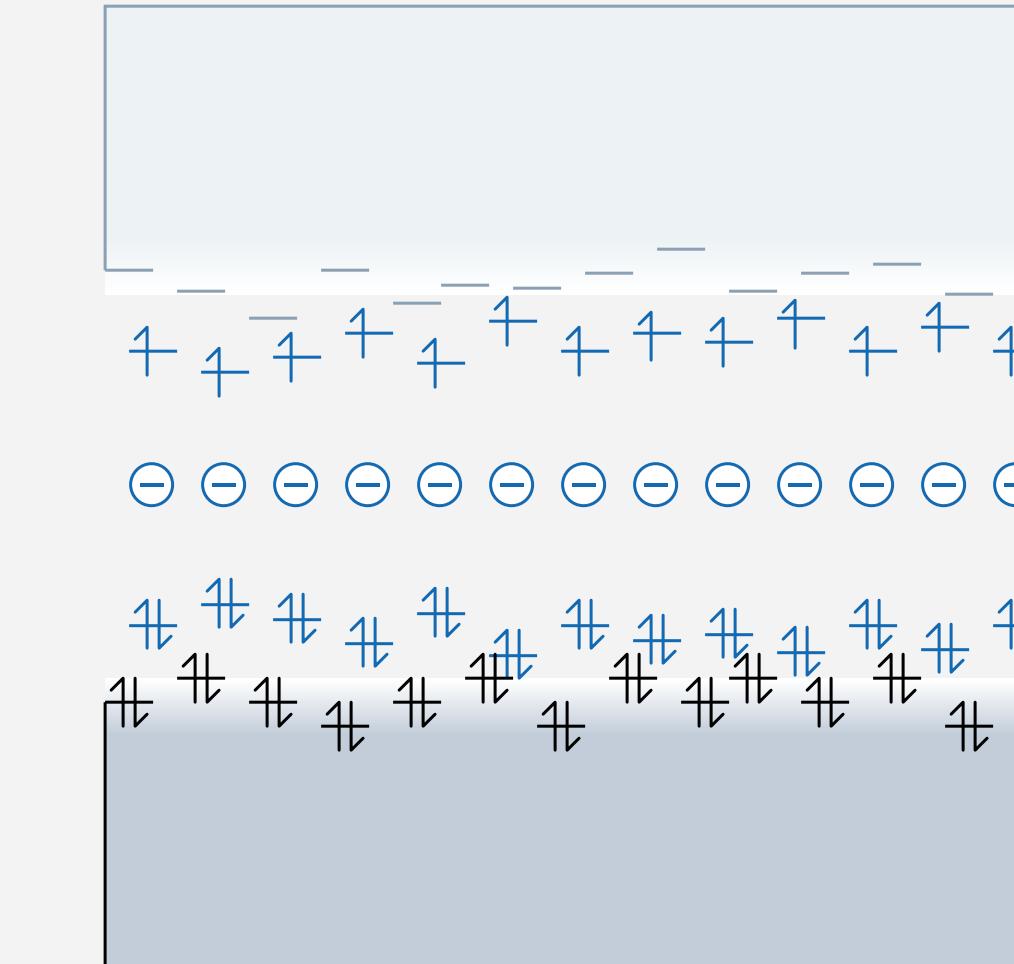
**p-type transport
active region**



amorphous material



**n-type transport
active region**



- **oxidation or reduction of π -conjugated systems generates charge carriers**
- **poly(acetylene) is an exception because it has degenerate ground states**
 - neutral solitons exist as defects at domain boundaries
 - spontaneous charge separation in an electric field possible
 - oxidation/reduction yields positive/negative soliton charge carriers
 - soliton charge carriers have a charge ($q = \pm e$), no spin ($s = 0$), plus a lattice defect
- **typical organic semiconductors do not have degenerate ground states**
 - spontaneous charge separation in an electric field is not observed
 - oxidation/reduction yields positive/negative polaron charge carriers
 - polarons have a charge ($q = \pm e$), a spin ($s = \frac{1}{2}$), plus a lattice defect
- **delocalization of polaron charge carriers interacting with neutral neighbors**
 - delocalization depends on static / dynamic disorder, crystallographic direction
 - formation of narrow bands (≤ 0.1 eV) in ordered domains at high charge densities
 - abrupt changes of electronic levels at crystalline/amorphous interfaces
- **fuzzy band edge with neutral and polaronic states is active transport region**

